



## 650nm Power changeable RED LASER MODULE - SYN-VFL18 Series

### Description

The is index guided 650 nm (Typ.) AlGaInP laser diode with low threshold current and high operating temperature. The low threshold current and short wavelength are achieved by a strained multiple quantum well active layer. The lasing wavelength is 640nm which is 8 times brighter than that of 660nm lasers. The is suitable for applications such as bar-code scanners, laser printer, and other optical information systems.

### Features

- ⊙ MQW 650nm FP LD
- ⊙ High output power
- ⊙ Low threshold current
- ⊙ Built-in InGaAsP monitor PD (P Type)
- ⊙ Wide temperature range operation  
(Tc= -10 to+65°C)
- ⊙ Package : As Drawing & Dimension information



### Application

- ⊙ Laser module
- ⊙ VFL (Visual Fault Locator)

### Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	Remark
LD Forward Current	IF(LD)	200	mA	
LD Reverse Voltage	VR(LD)	2	V	
PD Forward Current (For P Type)	IF(PD)	2	mA	
PD Reverse Voltage (for P Type)	VR(PD)	25	V	
Operating Temperature	TOP(LD)	-10 ~ +60	°C	
Storage Temperatur	TST	-40 ~ +80	°C	
Soldering Temperature/Time	-	240/10	°C/S	

### Optical & Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Remark
Output Power	Po	1	-	20	mW	
Operating Current (for P Type)	Iop	25	-	45	mA	1mW= Iop 20~25mA 5mW= Iop 35~45mA
Operating Current (for N Type)	Iop	35	-	145	mA	5mW= Iop 35~45mA 10mW= Iop 85~90mA 20mW= Iop 120~125mA 30mW= Iop 140~145mA
Operating Voltage	Vop	-	2.2	2.8	V	
Center Wavelength	$\lambda$	640	650	660	nm	
Spectral Width	$\Delta\lambda$	-	-	4	nm	
Monitor Current	Im	0.1	0.2	0.5	mA	
Rise/ Fall Time	Tr/Tf	-	-	0.5	ns	

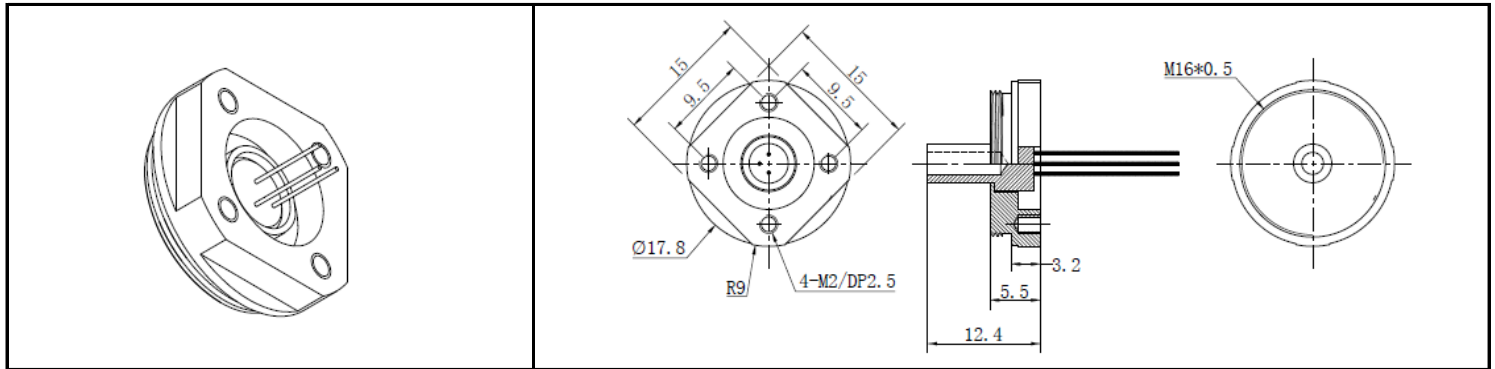


**Order Information - Base**

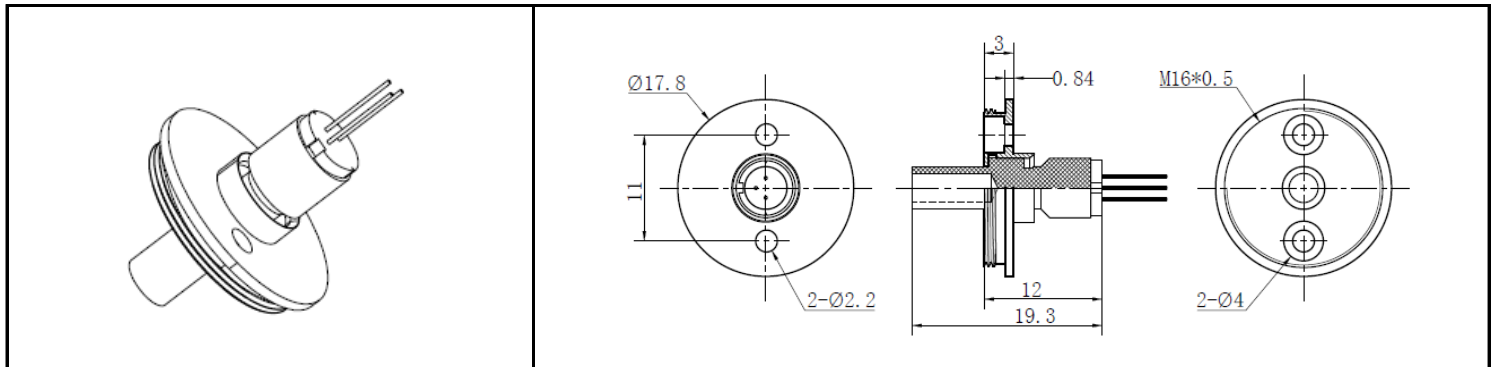
Band	Mode	Base Type	Power Range	P/N
SYN-	VFL18-B-	4 -	1mW-	SYN-VFL18-B-4-1mW
			5mW-	SYN-VFL18-B-4-5mW
			10mW-	SYN-VFL18-B-4-10mW
			20mW-	SYN-VFL18-B-4-20mW
			30mW-	SYN-VFL18-B-4-30mW
SYN-	VFL18-B-	2 -	1mW-	SYN-VFL18-B-2-1mW
			5mW-	SYN-VFL18-B-2-5mW
			10mW-	SYN-VFL18-B-2-10mW
			20mW-	SYN-VFL18-B-2-20mW
			30mW-	SYN-VFL18-B-2-30mW

**Drawing & Dimension - Base**

PN: SYN-VFL18-B-4-XXX



PN: SYN-VFL18-B-2-XXX



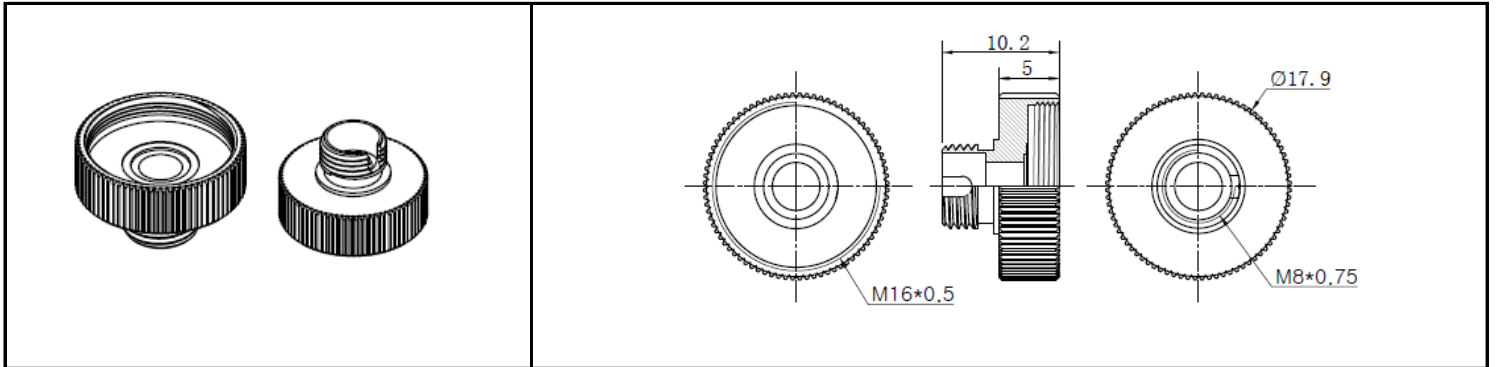
**Order Information - Adapters**

Band	Mode	Adaptor Type	P/N
SYN-	RMPDVFL18-P-	FC	SYN-RMPDVFL18-P-FC
		SC	SYN-RMPDVFL18-P-SC
		ST	SYN-RMPDVFL18-P-ST
		DIN	SYN-RMPDVFL18-P-DIN
		COM (FC & SC & ST)	SYN-RMPDVFL18-P-COM
		ALL (FC & SC & ST & DIN)	SYN-RMPDVFL18-P-ALL

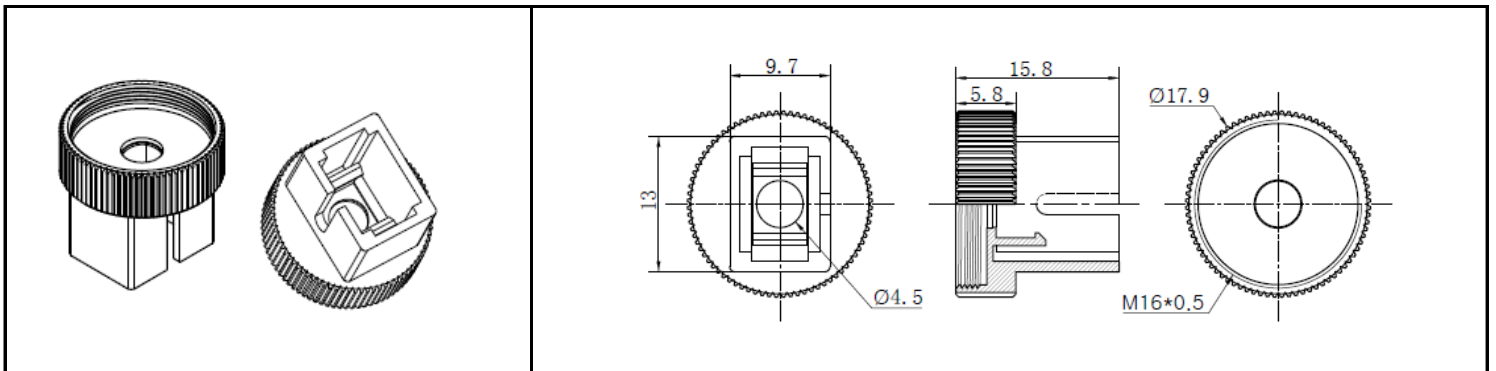


Drawing & Dimension - Adaptor

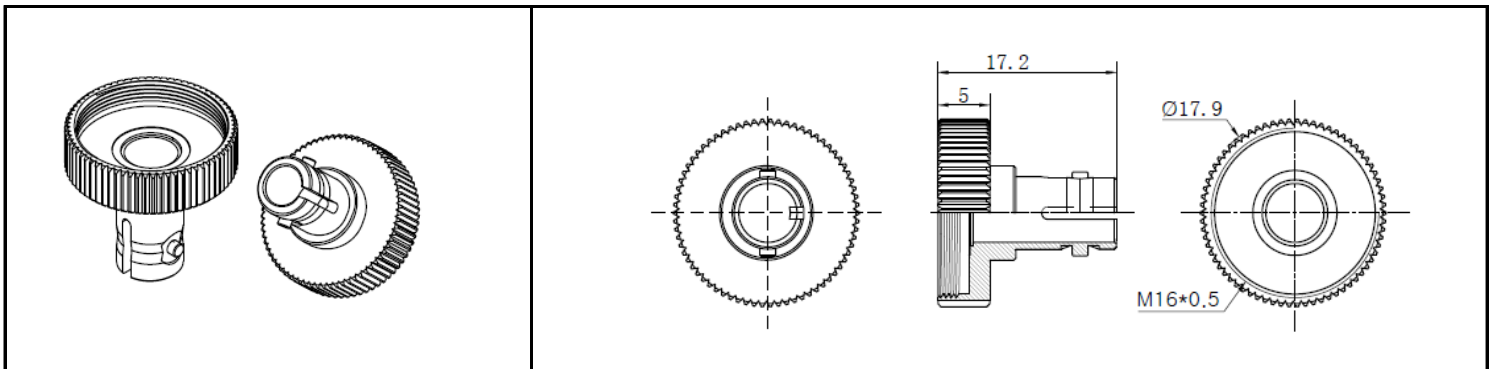
P/N : SYN-RMPDVFL18-P-FC



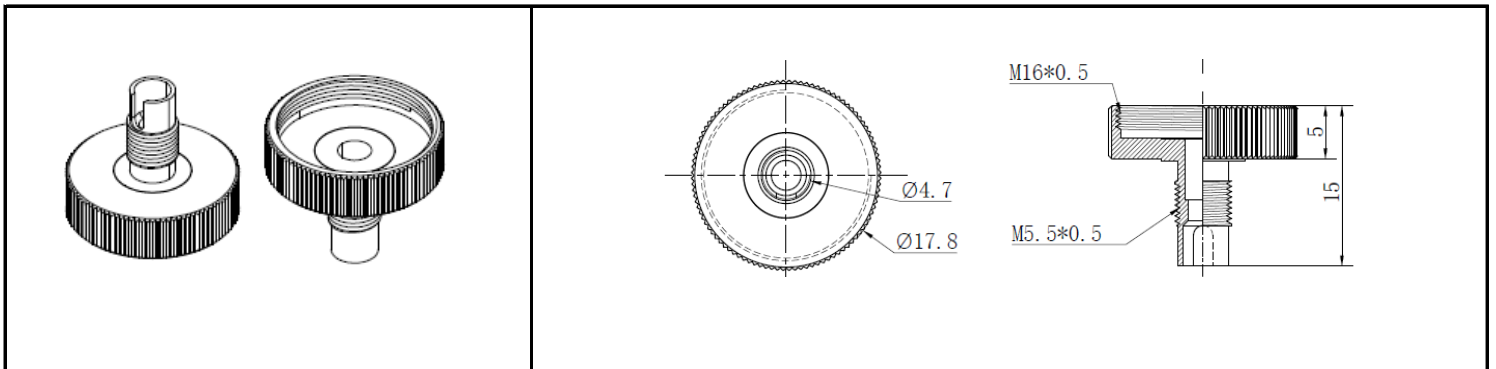
P/N : SYN-RMPDVFL18-P-SC



P/N : SYN-RMADVFL18-P-ST

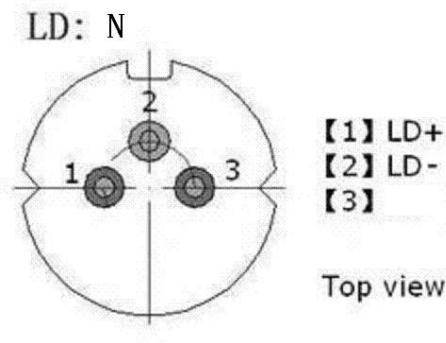
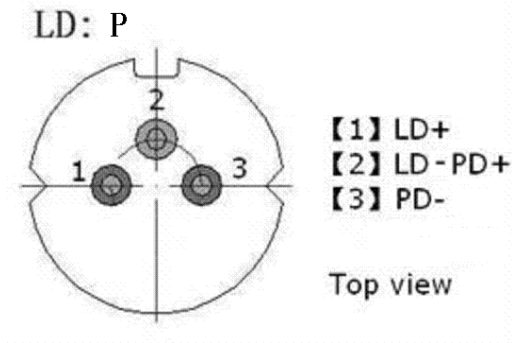


P/N : SYN-RMPDVFL18-P-DIN





Pin Assignment



Note:

P :Type Pin Applicable Power 1~5mw

N :Type Pin Applicable Power 5~20mw

Semiconductor lasers and detectors are Static sensitive components are vulnerable to Electrostatic discharge (ESD)and surge over Current (EOS) damage! Please contact with Static sensitive

